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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/675,574	09/30/2003	Kei Kanemoto	9319S-000544	9968
27572	7590 09/09/2004		EXAMINER	
	, DICKEY & PIERCE,	HA, NATHAN W		
P.O. BOX 8: BLOOMFIE	28 LD HILLS, MI 48303		ART UNIT	PAPER NUMBER
	,		2814	
			DATE MAILED: 09/09/200	4

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)				
Office Action Summary		10/675,574	KANEMOTO, KEI				
		Examiner	Art Unit				
		Nathan W. Ha	2814				
Period f	The MAILING DATE of this communication or Reply	appears on the cover sheet w	ith the correspondence address				
THE - External control	MAILING DATE OF THIS COMMUNICATION AND COMMUNICATION AND COMMUNICATION C	ON. R 1.136(a). In no event, however, may a i. It reply within the statutory minimum of this riod will apply and will expire SIX (6) MOI tatute, cause the application to become A	reply be timely filed ty (30) days will be considered timely. NTHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).				
Status							
1)⊠	Responsive to communication(s) filed on 3	<u> 0 January 2004</u> .					
2a)□	This action is FINAL . 2b)⊠	This action is non-final.					
3)	Since this application is in condition for allo	wance except for formal mat	ters, prosecution as to the merits is				
	closed in accordance with the practice und	er <i>Ex parte Quayle</i> , 1935 C.[). 11, 453 O.G. 213.				
Disposit	ion of Claims						
4)⊠	Claim(s) 1-6 is/are pending in the application	on.					
	4a) Of the above claim(s) is/are with	drawn from consideration.					
5)⊠	Claim(s) <u>2-6</u> is/are allowed.						
6)⊠	Claim(s) <u>1</u> is/are rejected.						
7)	Claim(s) is/are objected to.						
8)□	Claim(s) are subject to restriction ar	nd/or election requirement.					
Applicat	tion Papers						
9)[The specification is objected to by the Exan	niner.					
10)	The drawing(s) filed on is/are: a)	accepted or b) objected to	by the Examiner.				
	Applicant may not request that any objection to	the drawing(s) be held in abeya	nce. See 37 CFR 1.85(a).				
	Replacement drawing sheet(s) including the co	rrection is required if the drawing	y(s) is objected to. See 37 CFR 1.121(d).				
11)	The oath or declaration is objected to by the	e Examiner. Note the attache	d Office Action or form PTO-152.				
Priority	under 35 U.S.C. § 119						
a)	Acknowledgment is made of a claim for fore All b) Some * c) None of: 1. Certified copies of the priority docum 2. Certified copies of the priority docum 3. Copies of the certified copies of the application from the International Bu See the attached detailed Office action for a	nents have been received. nents have been received in a priority documents have beer reau (PCT Rule 17.2(a)).	Application No n received in this National Stage				
Attachme			979.446				
	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948		Summary (PTO-413) (s)/Mail Date				
3) 🔲 Info	rmation Disclosure Statement(s) (PTO-1449 or PTO/SE er No(s)/Mail Date	′	Informal Patent Application (PTO-152)				

Art Unit: 2814

DETAILED ACTION

Specification

1. The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed.

Claim Objections

Claims 2 and 5 are objected to because of the following informalities:
 Please remove phrase "from which the spacer layer is removed", in claim
 line 11, and claim 5, line 17. Appropriate correction is required.

Please replace the element "layer" with "film" in order to avoid any confusion since there are two distinguished layers with the same name in the claims; Claim 2, line 13, and claim 5 line 19.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claim 1 is rejected under 35 U.S.C. 103(a) as being unpatentable over Chen (US 2002/0076885) and in view of Chatterjee et al. (US 6,117,741, hereinafter, Chatterjee.)

Application/Control Number: 10/675,574

Art Unit: 2814

In regard to claim 1, in figs. 1C-1H, Chen discloses a method of manufacturing a semiconductor device, comprising:

forming a dummy gate layer 20, disposable gate (section [0020], line 1], above a semiconductor substrate 10 (fig.1C, section [0015], line 2);

forming a spacer layer 34 (section [0024], line 1) adjacent each side of the dummy gate layer (fig. 1C).

selectively forming a layer 44 above the substrate (fig. 1D);

forming a gate electrode 70 after removing the dummy gate layer (section [0032], lines 1-2 and figs. 1G-1H);

forming a source/drain regions 40 and 42 by introducing an impurity into the semiconductor substrate through the layer [section [0023]; and changing the silicon layer into a silicide layer (section [0027, lines 8-10.)

Chen, however, does not expressly disclose the material of layer 44 as epitaxial layer. The method of forming a silicon layer by epitaxial process is widely use in the art of making semiconductor layer in order to control the thickness of the layer since it is grown by single silicon crystalline silicon. For instance, Chatterjee, in figs. 1a-1j, discloses an analogous semiconductor device including a dummy gate 24 disposed on a substrate 14, sidewall spacers 28 by the sides of the gate. Chatterjee further discloses forming an epitaxial 30 on the substrate in order to control the thickness of the silicon layer (see col.5, lines 24-29.)

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention was made to recognize the obviousness of using well

Application/Control Number: 10/675,574

Art Unit: 2814

known silicon layer as an epitaxial layer as taught by Chatterjee at the surface of the device in order to control the thickness of the layer since it is grown by single crystalline silicon material.

Allowable Subject Matter

- 5. Claims 2-6 are allowed.
- 6. The following is an examiner's statement of reasons for allowance:

The primary reason for the indication of the allowability of the above claims is the inclusion therein, in combination as currently claimed, of the limitation of the use of the step of forming the extension region by introducing an impurity in to the substrate at the spacer's location after the spacers have being removed. This limitation is found in the above claims and is neither disclosed nor taught by the prior art of record, alone or in combination.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Nathan W. Ha whose telephone number is (571) 272-1707. The examiner can normally be reached on M-TH 8:00-7:00(EST).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor. Wael Fahmy can be reached on (571) 272-1705. The fax

Art Unit: 2814

phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Nathan Ha

August 30, 2004

John U. to